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UNISYS

Interoffice Memorandum

Tα

T. Miccolis

Department

Code 300.1

From

K. Sahu (55\_

Department 7809

Subject

Radiation Report on UDS2983

SMEX Common Buy Part No. 5962-8851902VA

PPM-91-551

Date

September 27, 1991

Location

Lanham

Telephone

731-8954

Location

Lanham

cc

B. Fafaul/311

D. Krus

A. Casasnovas

M. Fowler

A. Moor

A radiation evaluation was performed on UDS2983 to determine the total dose tolerance of these parts. A brief summary of the test results is provided below. For detailed information, refer to Tables I through IV and Figure 1.

The total dose testing was performed using a cobalt-60 gamma ray source. During the radiation testing, eight parts were irradiated under bias (see Figure 1 for bias configuration), and two parts were used as control samples. The total dose radiation steps were 25, 50, 75 and 100 krads. After 100 krads, parts were annealed at 25°C for 24 and 168 hours, and then irradiation was continued to 200 and 300 krads (cumulative). The dose rate was between 1.3 - 5.0 krads/hour, depending on the total dose level (see Table II for radiation schedule). After each radiation exposure and annealing treatment, parts were electrically tested according to the test conditions and the specification limits listed in Table III. These tests included a functional test after each radiation and annealing step.

All (8) parts passed all initial electrical measurements and all functional tests to 300 krads. However, after the first radiation exposure of 25 krads, all parts exceeded the 4V measurement limit of the test equipment for VSAT1. In addition, most outputs of all parts failed to meet the minimum specification limit of -200mA for IOUT. After 50 krads and above, all outputs of all parts had IOUT readings of approximately -1mA and VSAT1 continued to exceed 4V. Strangely, VSAT2 and VSAT3 failures were observed on four parts after 25 krads, but no VSAT2 or VSAT3 failures were observed at any other radiation step up to 300 krads.

Table IV provides the mean and standard deviation values for each parameter after different radiation exposures and annealing treatments. It also provides a summary of the functional test results after each radiation/annealing step.

Any further details about this evaluation can be obtained upon request. If you have any questions, please call me at 301-731-8954.

## TABLE I. Part Information

Generic Part Number: UDS2983

SMEX Common Buy Part Number: 5962-8851902VA

SMEX Common Buy Control Number: 1691

Charge Number: C90241

Manufacturer: Sprague Electric Co.

Quantity Procured: 125

Lot Date Code: 9026A

Quantity Tested: 10

Serial Numbers of 3, 4, 5, 6, Radiation Samples: 7, 8, 9, 10

Serial Numbers of Control Samples: 1, 2

Part Function: High-Current/High-Voltage Driver

Part Technology: Bipolar

Package Style: 18-Pin DIP

Test Engineer: C. Nguyen

TABLE II. Radiation Schedule

EVENTS	DATE
1) Initial Electrical Measurements	03/20/91
2) 25 krads irradiation @ 1350 rads/hr	04/21/91
Post 25 krads Electrical Measurements	04/22/91
3) 50 krads irradiation @ 1390 rads/hr	04/22/91
Post 50 krads Electrical Measurements	04/23/91
4) 75 krads irradiation @ 1315 rads/hr	04/23/91
Post 75 krads Electrical Measurements	04/24/91
5) 100 krads irradiation @ 1390 rads/hr	04/24/91
Post 100 krads Electrical Measurements	04/25/91
6) 24 hrs annealing	04/25/91
Post 24 hr Electrical Measurements	04/26/91
7) 168 hrs annealing	04/25/91
Post 168 hr Electrical Measurements	05/02/91
8) 200 krads irradiation @ 5555 rads/hr	05/02/91
Post 200 krads Electrical Measurements	05/03/91
9) 300 krads irradiation @ 1515 rads/hr	05/03/91
Post 300 krads Electrical Measurements	05/06/91

## Notes:

<sup>-</sup> All parts were radiated under bias at the cobalt-60 gamma ray facility at GSFC.

<sup>-</sup> All electrical measurements were performed off-site at 25°C. - Annealing was performed at 25°C under bias.

Table III. Electrical Characteristics of UDS2983

Unless otherwise specified:

TEST	CONDITIONS	LIM	UNITS		
		Min	Маж		
ICC	V <sub>IN</sub> =2.4V	0	10.0	mΛ	
ICEX	V <sub>IN</sub> =0.25V, V <sub>OUT</sub> =0V	o	200	uД	
IR	VCC=80V, VOUT=80V , Vinto LSY	0	50	uA	
$\overline{\mathbf{v_F}}$	I <sub>F</sub> =200mA, V <sub>IN</sub> =V <sub>CC</sub> =OPEN	0	1.75	v	
V <sub>SAT1</sub>	I <sub>OUT</sub> =-350mA, V <sub>IN</sub> =2.4V,V <sub>CC</sub> =5V	0	2.0	v	
v <sub>SAT2</sub>	I <sub>OUT</sub> =-200mA, V <sub>IN</sub> =2.4V,V <sub>CC</sub> =5V	o	1.9	v	
V <sub>SAT3</sub>	I <sub>OUT</sub> =-100mA, V <sub>IN</sub> =2.4V, V <sub>CC</sub> =5V	0	1.8	v	
IINL	VCC=80V,VIN=0V	-10	10	υA	
7INH1	V <sub>CC</sub> =80V, V <sub>IN</sub> =2.4V	0	295	uA	
I <sub>INH2</sub>	V <sub>CC</sub> =80V, V <sub>IN</sub> =3.85V	0	600	uА	
INH3	V <sub>CC</sub> =80V, V <sub>IN</sub> =12V	0	2.3	mA	
LOUT	V <sub>CE</sub> =2.2V, V <sub>IN</sub> =2.4V, V <sub>CC</sub> =5V	<b>∺500</b>	-200	mА	
*TPLH	V <sub>CC</sub> =35V,R <sub>L</sub> = 175 OHM	0	2.0	us	
(TP <sub>HL</sub>	V <sub>CC</sub> =35V,R <sub>L</sub> = 175 OHM	0	10.0	us	

Note: Functional Test performed at 10KHz, Vcc=80V,  $V_{TH}$ =15V,  $V_{TL}$ =0V,  $V_{OH}$ =25V,  $V_{OL}$ =25V.

The TPLH and TPHL tests were preformed at  $\rm V_{CC}=35V$  and  $\rm R_L=175$  OHM, due to the limitation of the tester.

TABLE IV: Summary Electrical Measurements after
Total Dose Exposures and Annealing for UDS2983 1/, 2/

							Tota	l Dos	e Ex	pesur	e (k	rads) Anneal				aling		Total Dose (krads)			
				Initials		25		50		75		100		24 hrs		168	hrs	200	200		00
Paramet	ers	Spec. min	Limits max	mean	sd	mean	sd	mean	sd	mean	sc.	mean	sd	mean	s <b>ೆ</b>	mean	sd	mean	ad	mean Pass	sd
Function	nal			Pass		Pass		Pass		Pass		Pass		Pass		Pass		Pass 3.8	0.1	3.7	0.1
ICC	mA	0	10	5.0	6.1	4.0	0.1	3.9	0.1	3.9	0.1	3.9	0.1	8,9	0.1	3.9	0.1				<del>!</del>
ICEX	uA.	0	200	D	0	.01	.01	.01	.01	03	.01	.04	.01	.03	.01	.01	0	.3	1	0.1	.03
IR	uА	0	50	0	0	0	0_	0	0	0	0	0	0_	0	0	0	0	0		200 100 100 100	1
VE	v	0	1.75	1.1	.05	1.2	.05	1.2	.04	1.2	.04	1.2	0.1	1.2	0.1	1.3	0.1	1.3	0.1	1.3	0.1
VSAT1	v	0	2.0	1.83	.02	>4	_	<b>&gt;</b> 4	L	>4 -		>4		>4		>4		>4		>4	
VSAT2		0	1.9	1,64	.03	1.9	0.4	1.69	.03	1.68	.02	1.67	.02	1.70	.02	1.71	.03	1.68	.03	1,69	
VSAT3	v	- 0	1.8	1.50	_	2.0	0.4	1.56	.01	1.54	.02	1.55	.02	1,56	.02	1.9	-	1,55	.03	1.56	· · · · · ·
IIL	uA	-10	10	0	0	0	0	0	0	0	0	02	.01	0	0	O	0	.09	.04	05	1
	uA	0	295	148	3	147	4	142	3	142	3	141	3	141	3	141	. 3	140	3_	139	5
17H1	uA.		600	337	5	335	5	331	7	§ <b>32</b> 8	6	329	5	325	7_	32B	8	324	5	320	7
11H2	EA	- 0	2.3	1.4		1,4	.05	1.7	.04	1.4	.03	1.4	.04	1.4	.03	1.4	.04	1.4	.03	1.4	.03
IIE3		-500	-200	-454	1	-180	70	-1.2	.2	-1.0	.2	-1.0	.2	=1.0	.2	-4.0	3.0	-1.0	.2_	-1.0	-
1007	A,n	0	2	.31	.01	36	.02	_38	.07	.40	, C 3	.40	.04	,41	.05	:40	.05	.48	.03	.40	.03
TPLH TPKL	us us	0 -	10	4.9	0.2	1,7	0.2	1.4	C.1	1.0	0.1	1.1	0.1	1,1	0.1	1.3	0.1	0.9	0.1	0.9	C.1

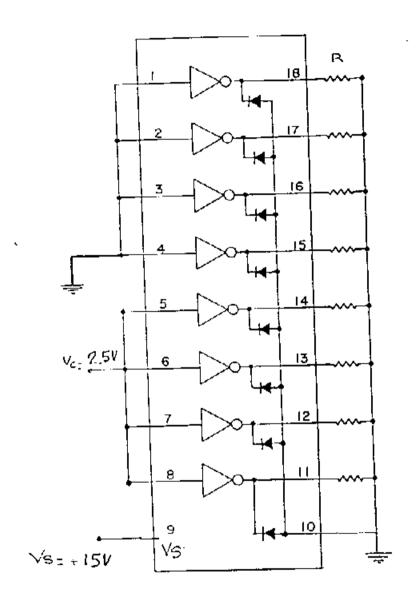
## Notes:

<sup>1/</sup> The mean and standard deviation values were calculated over the eight parts irradiated in this testing. The control samples remained constant throughout the testing and are not included in this table.

<sup>2/ &#</sup>x27;>4' for VSAT1 in Table IV indicates that parts were exceeding the 4V upper limit that the test equipment could measure for this parameter.

Figure 1. Radiation Bias Circuit for UDS2983

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AU. R = 1K1 + 5% 14W